

NOT RECOMMENDED FOR NEW DESIGN **USE DMN53D0LT**



DMN55D0UT

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max
50V	4Ω @ V _{GS} = 4V	160mA

Features and Benefits

- Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- ESD Protected Gate to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor driving
- Power management functions
- Load switching

Mechanical Data

- Package: SOT523
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram

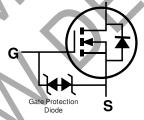


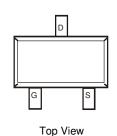




Top View

SOT523





Equivalent Circuit

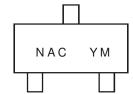
Ordering Information (Note 4)

Ī	Bart Ward an	Bardiana	Packing		
	Part Number	Package	Qty.	Carrier	
	DMN55D0UT-7	SOT523	3,000	Tape & Reel	

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



NAC = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: J = 2022) M = Month (ex: 6 = June)

Date Code Kev

Year	2008		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	V		J	K	L	М	N	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	50	V
Gate-Source Voltage	V _{GSS}	±12	V
Drain Current (Note 5) Continuous	ID	160	mA
Pulsed Drain Current (Note 5)	I _{DM}	560	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient	Reja	625	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

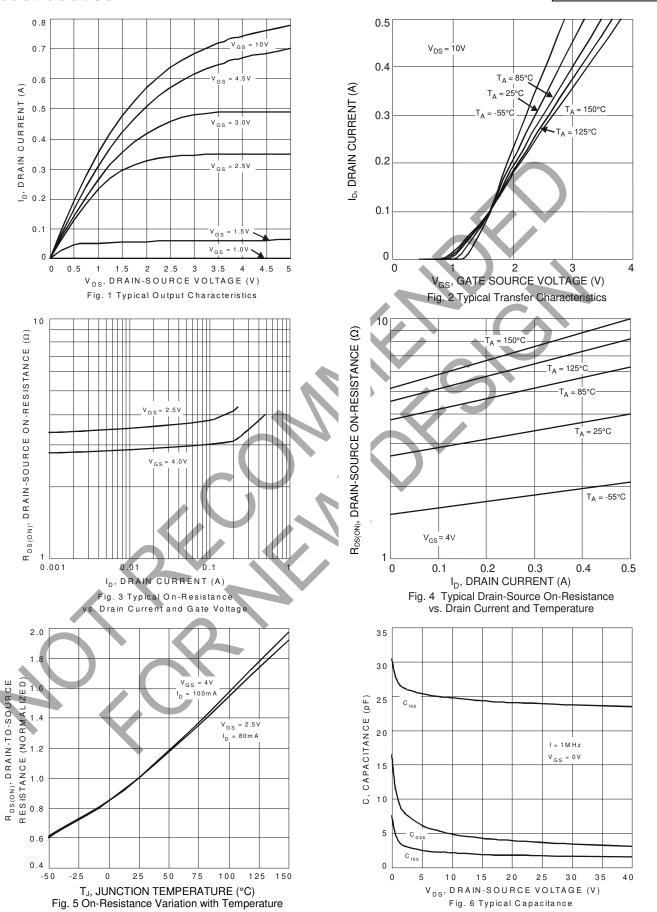
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)	Syllibol	IVIIII	Тур	IVIAX	Unit	Test Condition
Drain-Source Breakdown Voltage	BV _{DSS}	50			V	V _{GS} = 0V, I _D = 250μA
Zero Gate Voltage Drain Current	Ipss	_		1.	μΑ	V _{DS} = 50V, V _{GS} = 0V
Gate-Source Leakage	Igss	_		1.0 5.0	μΑ	$V_{GS} = \pm 8V, V_{DS} = 0V$ $V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)						140 =1=1, 150 01
Gate Threshold Voltage	V _{GS(TH)}	0.7	0.8	1.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$
Otatia Busia Ocuma On Busiatana			3.1	4	_	V _{GS} = 4V, I _D = 100mA
Static Drain-Source On-Resistance	RDS(ON)	_	4	5	Ω	V _{GS} = 2.5V, I _D = 80mA
Forward Transconductance	grs	180	_		mS	V _{DS} = 10V, I _D = 100mA, f = 1.0kHz
Diode Forward Voltage	VsD		0.70	1.3	V	V _{GS} = 0V, I _S = 100mA
DYNAMIC CHARACTERISTICS (Note 7)		•	•	•	•	
Input Capacitance	Ciss	_	25	_	pF	
Output Capacitance	Coss		5		рF	$V_{DS} = 10V, V_{GS} = 0V, f = 1.0MHz$
Reverse Transfer Capacitance	Crss		2.1		pF	
Gate Resistance	Rg	_	500	_	Ω	$f = 1MHz$, $V_{GS} = 0V$, $V_{DS} = 0V$
Total Gate Charge (V _G s = 4V)	Qg	_	295	_	рС	
Total Gate Charge (V _{GS} = 8V)	Qg	_	636	_	рС	V _{DS} = 10V,
Gate-Source Charge	Q _{GS}	_	72	_	рС	$I_D = 100 \text{mA}$
Gate-Drain Charge	QgD	_	18	_	рС	
Turn-On Delay Time	td(on)	_	6.0	_	ns	
Turn-On Rise Time	t _R	_	4.4	_	ns	$V_{DD} = 10V, V_{GS} = 4V,$
Turn-Off Delay Time	tD(OFF)	_	23.4	_	ns	$R_G = 25\Omega$, $I_D = 100mA$
Turn-Off Fall Time	tF	_	11.0	_	ns	

Notes:

- 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.6. Short duration pulse test used to minimize self-heating effect.7. Guaranteed by design. Not subject to product testing.









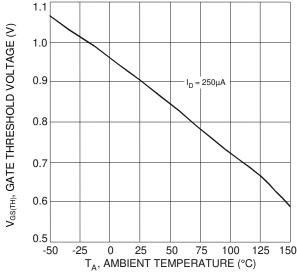
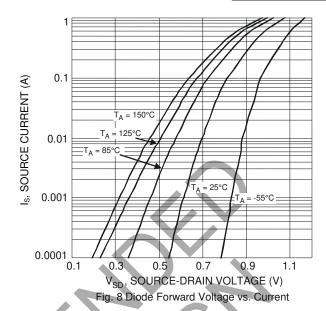
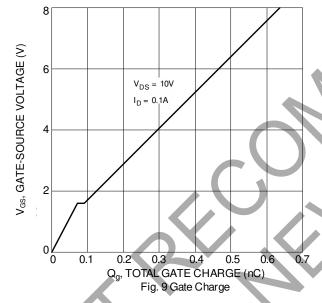


Fig. 7 Gate Threshold Variation vs. Ambient Temperature





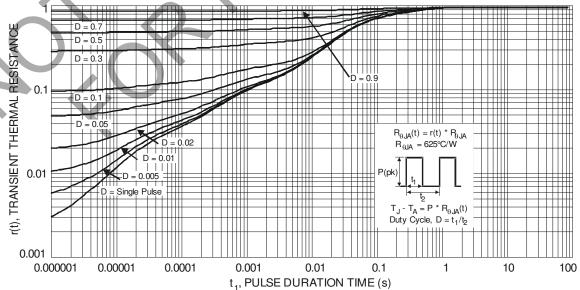


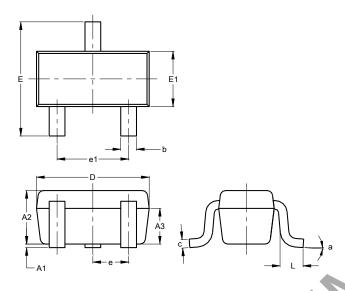
Fig. 10 Transient Thermal Response



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523

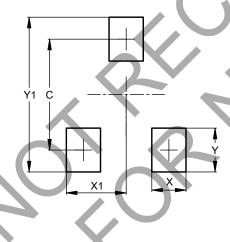


SOT523							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.60	0.80	0.75				
A3	0.45	0.65	0.50				
b	0.15	0.30	0.22				
С	0.10	0.20	0.12				
D	1.50	1.70	1.60				
E	1.45	1.75	1.60				
E1	0.75	0.85	0.80				
е	0.50 BSC						
e1	0.90	1.10	1.00				
L	0.20	0.40	0.33				
а	0°		8°				
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523



Dimensions	Value (in mm)			
С	1.29			
Х	0.40			
X1	0.70			
Υ	0.51			
V1	1 80			



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